Chapter 11 Frequency Response

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- 11.2 High-Frequency Models of Transistors
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- 11.9 Additional Examples

Chapter Outline

Fundamental Concepts

- Bode's Rules
- Association of Poles with Nodes
- Miller's Theorem



High-Frequency Models of Transistors

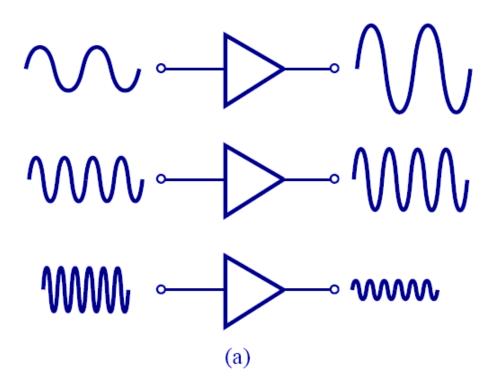
- Bipolar Model
- MOS Model
- Transit Frequency

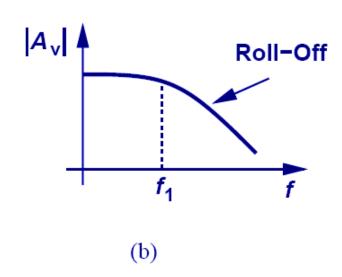


Frequency Response of Circuits

- CE/CS Stages
- CB/CG Stages
- Followers
- Cascode Stage
- Differential Pair

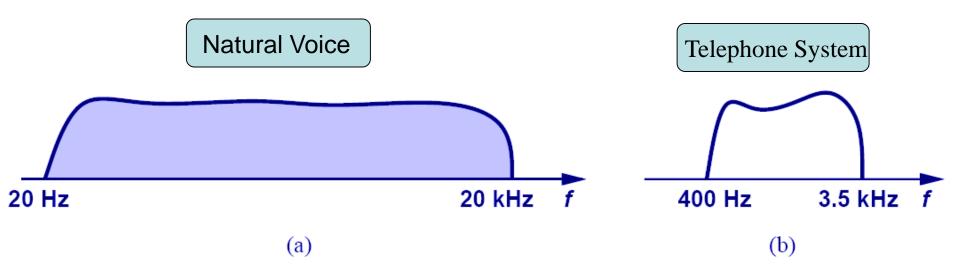
High Frequency Roll-off of Amplifier





As frequency of operation increases, the gain of amplifier decreases. This chapter analyzes this problem.

Example: Human Voice I



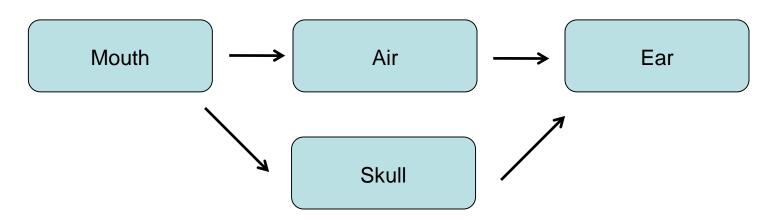
➤ Audible sound spans a frequency range from 20Hz to 20kHz. However, conventional telephone system passes frequencies from 400Hz to 3.5kHz over which human voice can produce.

Example: Human Voice II

Path traveled by the human voice to the voice recorder

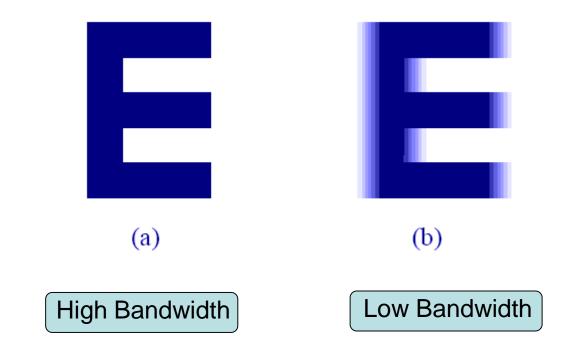


Path traveled by the human voice to the human ear



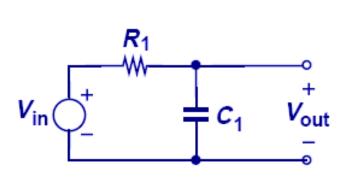
Since the paths are different, the results will also be different.

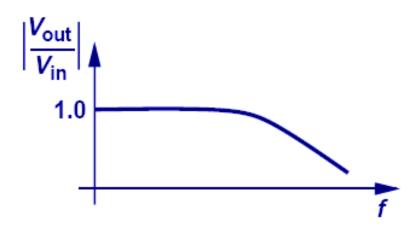
Example: Video Signal



Video signals without sufficient bandwidth become fuzzy as they fail to abruptly change the contrast of pictures from complete white into complete black. (The case with analog raster scan)

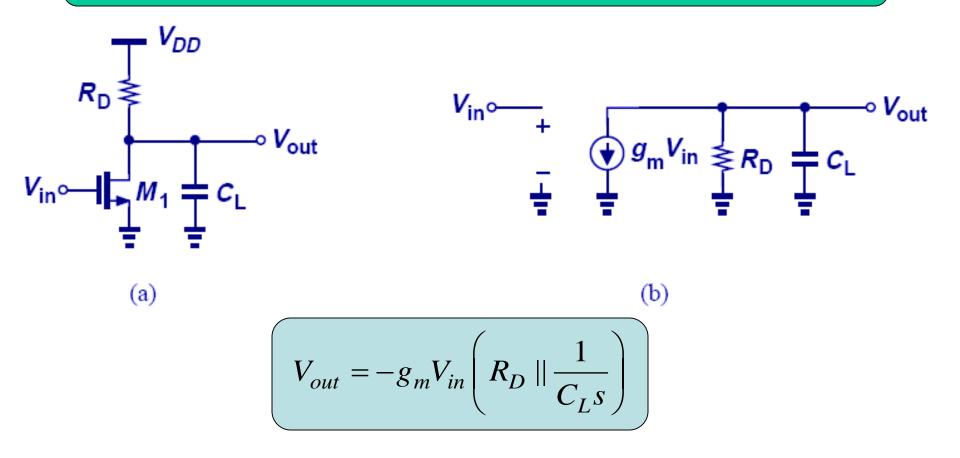
Gain Roll-off: Simple Low-pass Filter





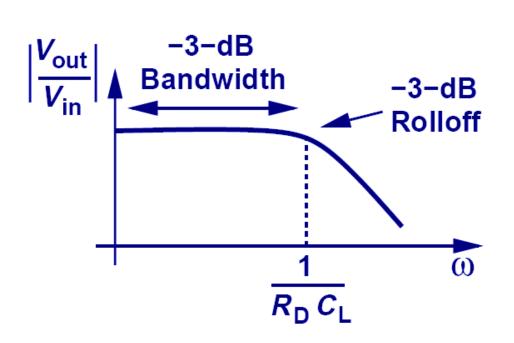
➤ In this simple example, as frequency increases the impedance of C₁ decreases and the voltage divider consists of C₁ and R₁ attenuates V_{in} to a greater extent at the output.

Gain Roll-off: Common Source



➤ The capacitive load, C_L, is the culprit for gain roll-off since at high frequency, it will "steal" away some signal current and shunt it to ground.

Frequency Response of the CS Stage



$$H(s) = \frac{V_{out}}{V_{in}}(s)$$

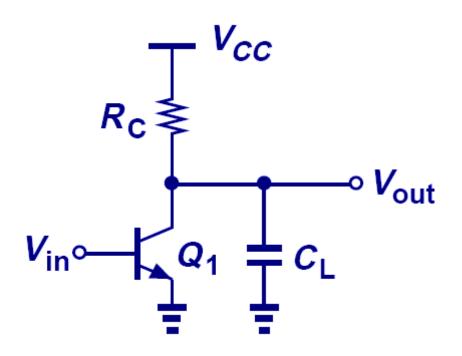
$$= -g_m \left(R_D \left\| \frac{1}{C_L s} \right) \right\}$$

$$= \frac{-g_m R_D}{R_D C_L s + 1}$$

$$\left| \frac{V_{out}}{V_{in}} \right| = \frac{g_m R_D}{\sqrt{R_D^2 C_L^2 \omega^2 + 1}}$$

At low frequency, the capacitor is effectively open and the gain is flat. As frequency increases, the capacitor tends to a short and the gain starts to decrease. A special frequency is $\omega=1/(R_DC_1)$, where the gain drops by 3dB.

Example: Figure of Merit



$$F.O.M. = \frac{Gain \times Bandwidth}{Power Consumption}$$

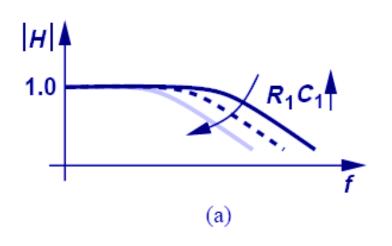
$$= \frac{g_m R_C \times \frac{1}{R_C C_L}}{I_C V_{CC}}$$

$$= \frac{\frac{I_C}{V_T} R_C \times \frac{1}{R_C C_L}}{I_C V_{CC}}$$

$$= \frac{1}{V_T V_{CC} C_L}$$

This metric quantifies a circuit's gain, bandwidth, and power dissipation. In the bipolar case, low temperature, supply, and load capacitance mark a superior figure of merit.

Example: Relationship between Frequency Response and Step Response



$$V_{\text{out}}$$
 t
(b)

$$\left|H\left(s=j\omega\right)\right| = \frac{1}{\sqrt{R_1^2 C_1^2 \omega^2 + 1}}$$

$$V_{out}(t) = V_0 \left(1 - \exp \frac{-t}{R_1 C_1} \right) u(t)$$

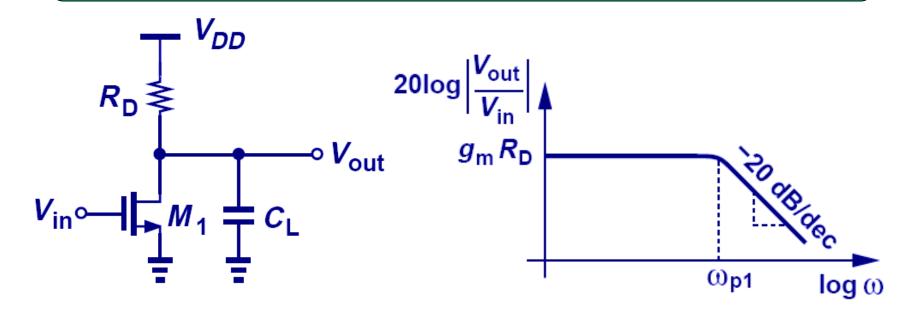
➤ The relationship is such that as R₁C₁ increases, the bandwidth *drops* and the step response becomes *slower*.

Bode Plot

$$H(s) = A_0 \frac{\left(1 + \frac{s}{\omega_{z1}}\right)\left(1 + \frac{s}{\omega_{z2}}\right)\cdots}{\left(1 + \frac{s}{\omega_{p1}}\right)\left(1 + \frac{s}{\omega_{p2}}\right)\cdots}$$

- \triangleright When we hit a zero, $ω_{zj}$, the Bode magnitude rises with a slope of +20dB/dec.
- \triangleright When we hit a pole, $ω_{pj}$, the Bode magnitude falls with a slope of -20dB/dec

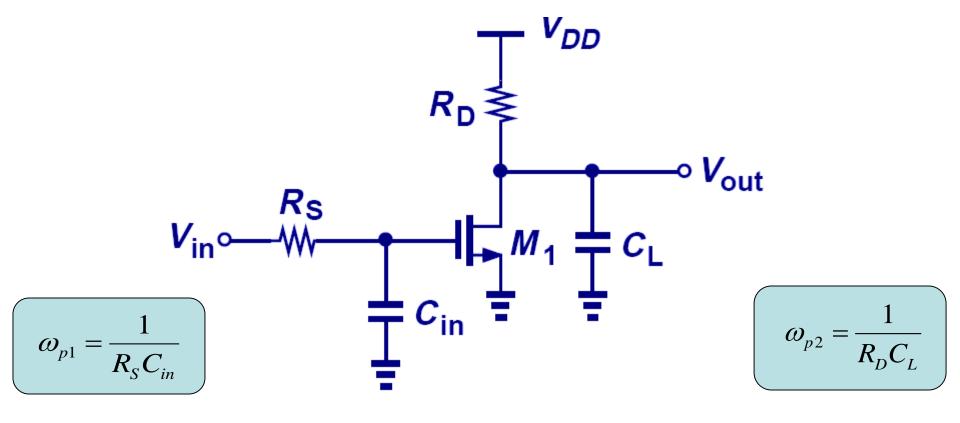
Example: Bode Plot



$$\omega_{p1} = \frac{1}{R_D C_L}$$

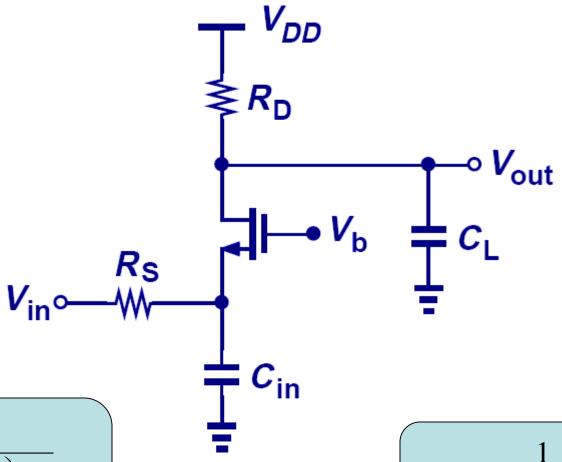
The circuit only has one pole (no zero) at $1/(R_DC_L)$, so the slope drops from 0 to -20dB/dec as we pass ω_{p1} .

Pole Identification Example I



$$\left| \frac{V_{out}}{V_{in}} \right| = \frac{g_m R_D}{\sqrt{\left(1 + \omega^2 / \omega_{p1}^2\right) \left(1 + \omega^2 / \omega_{p2}^2\right)}}$$

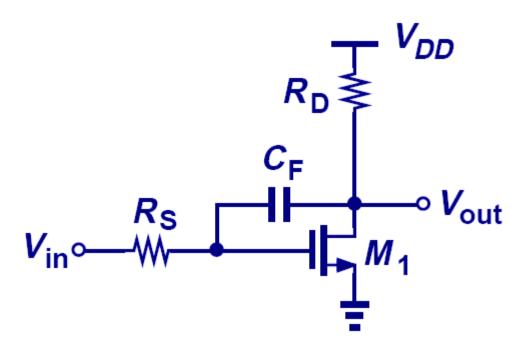
Pole Identification Example II



$$\omega_{p1} = \frac{1}{\left(R_S \parallel \frac{1}{g_m}\right)C_{in}}$$

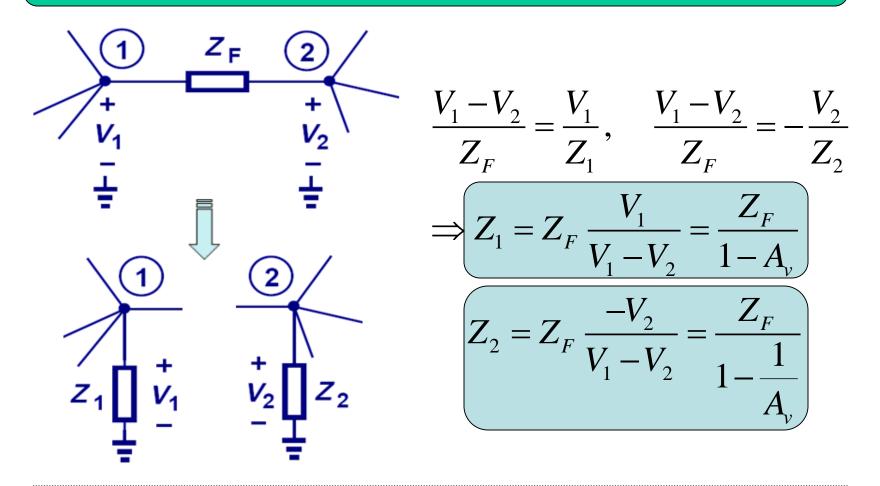
$$\omega_{p2} = \frac{1}{R_D C_L}$$

Circuit with Floating Capacitor



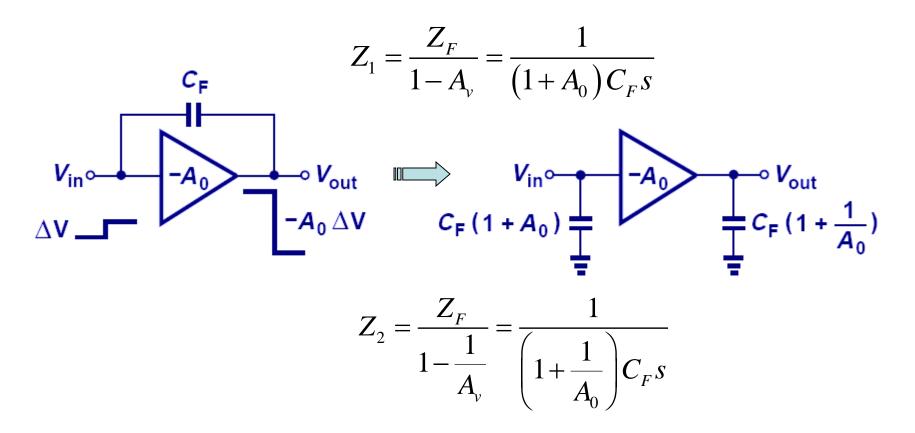
- ➤ The pole of a circuit is computed by finding the effective resistance and capacitance from a node to GROUND.
- The circuit above creates a problem since neither terminal of C_F is grounded.

Miller's Theorem



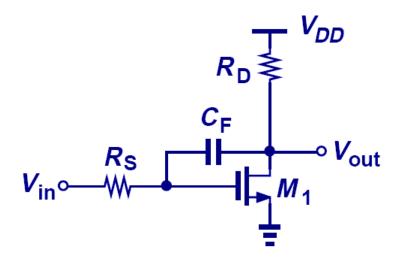
If A_v is the gain from node 1 to 2, then a floating impedance Z_F can be converted to two grounded impedances Z_1 and Z_2 .

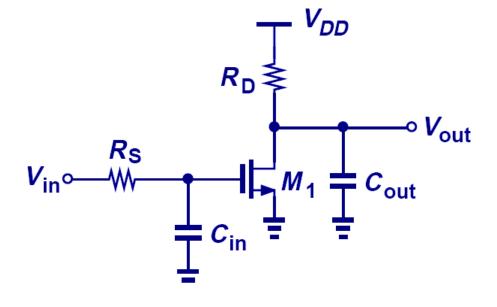
Miller Multiplication



With Miller's theorem, we can separate the floating capacitor. However, the input capacitor is larger than the original floating capacitor. We call this Miller multiplication.

Example: Miller Theorem

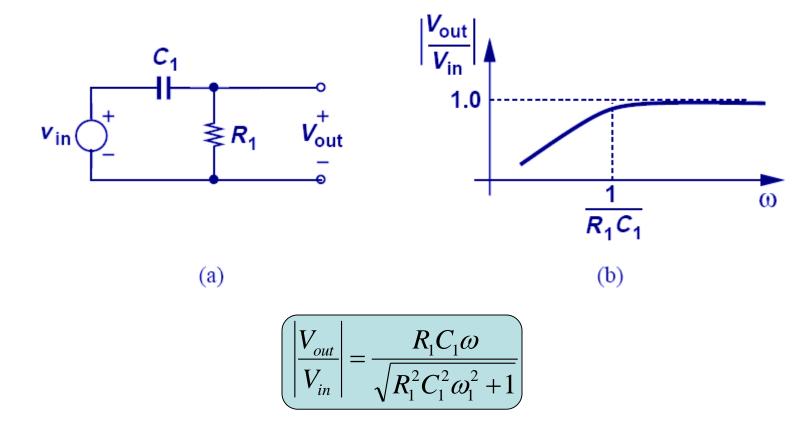




$$\omega_{in} = \frac{1}{R_S (1 + g_m R_D) C_F}$$

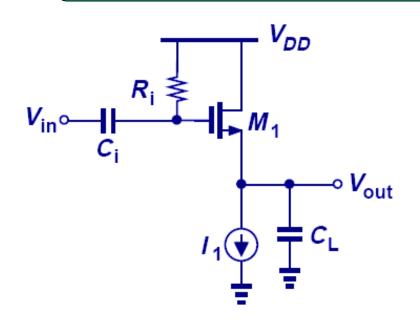
$$\omega_{out} = \frac{1}{R_D \left(1 + \frac{1}{g_m R_D}\right) C_F}$$

High-Pass Filter Response



The voltage division between a resistor and a capacitor can be configured such that the gain at low frequency is reduced.

Example: Audio Amplifier



$$R_i = 100 \text{ k}\Omega$$

$$g_m = 1/200 \Omega$$

$$\frac{1}{R_i C_i} \le 2\pi \times (20 \text{Hz})$$

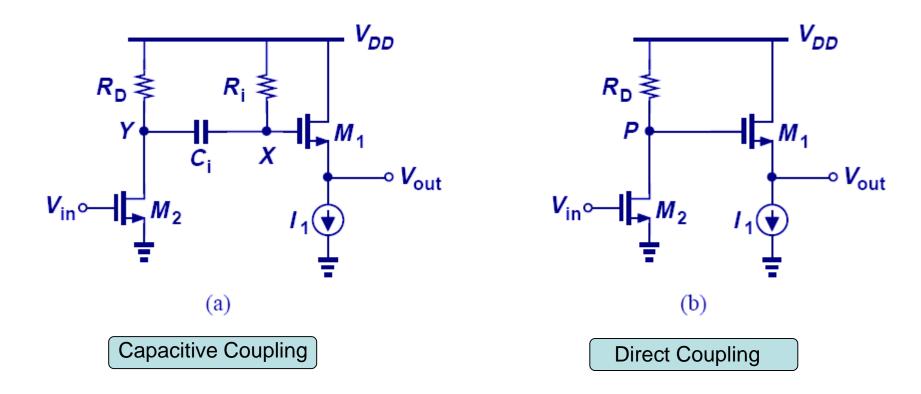
$$\Rightarrow C_i \ge \frac{1}{100k \times 2\pi \times 20} = 79.6 \text{nF}$$

$$\omega_{p,out} = \frac{g_m}{C_L} \ge 2\pi \times (20 \text{kHz})$$

$$\Rightarrow C_L \le \frac{1}{200 \times 2\pi \times 20 \text{k}} = 39.8 \text{nF}$$

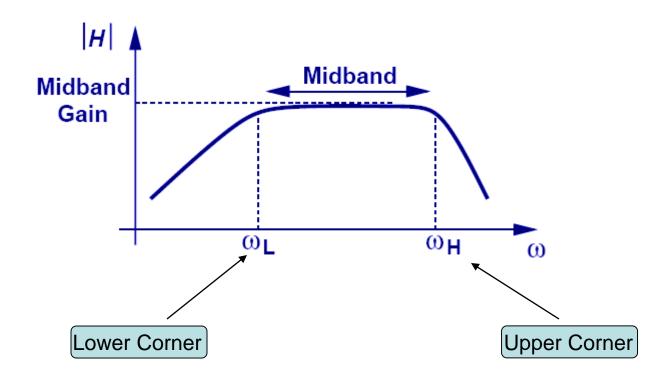
In order to successfully pass audio band frequencies (20 Hz-20 kHz), large input and small output capacitances are needed.

Capacitive Coupling vs. Direct Coupling

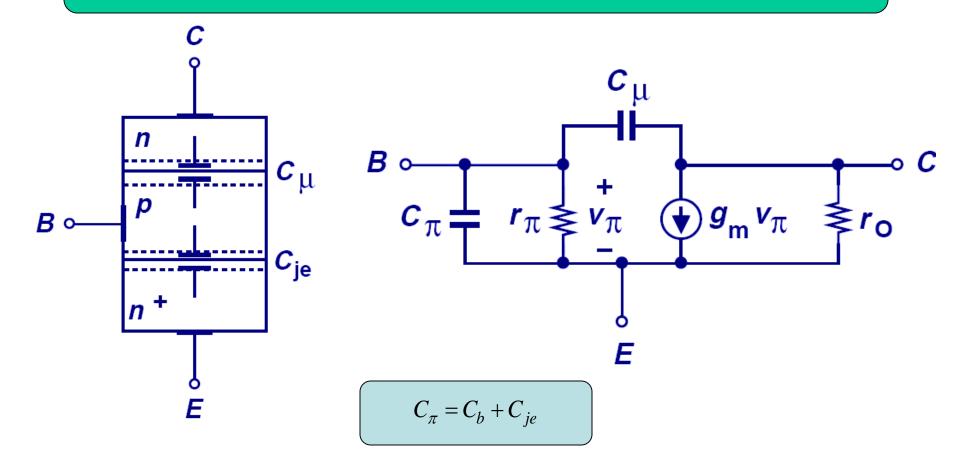


- Capacitive coupling, also known as AC coupling, passes AC signals from Y to X while blocking DC contents.
- This technique allows independent bias conditions between stages. Direct coupling does not.

Typical Frequency Response

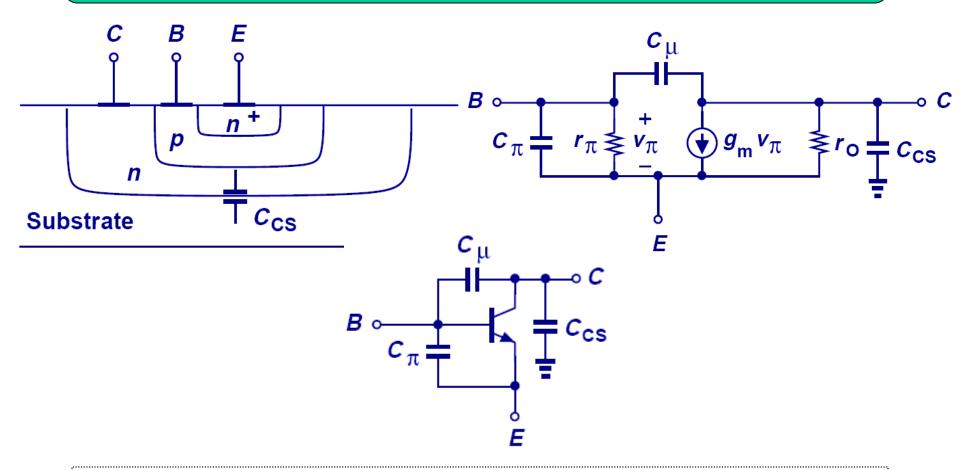


High-Frequency Bipolar Model



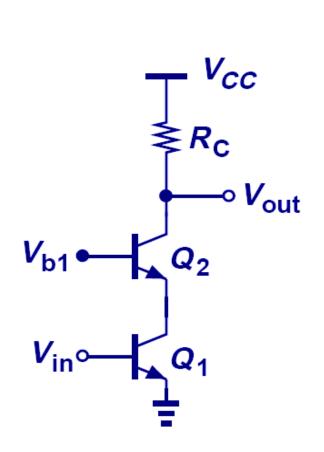
At high frequency, capacitive effects come into play. C_b represents the base charge, whereas C_{μ} and C_{je} are the junction capacitances.

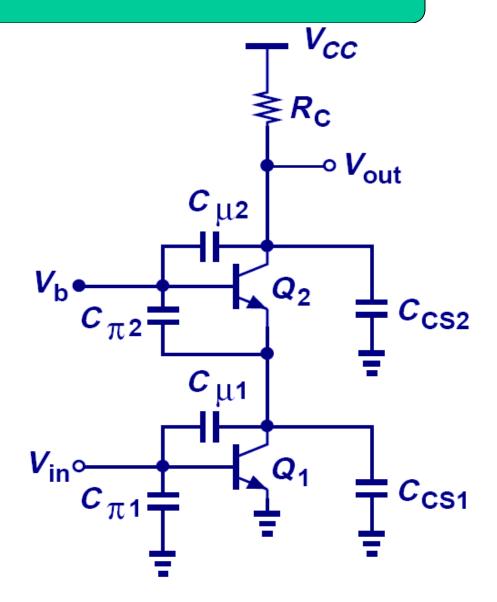
High-Frequency Model of Integrated Bipolar Transistor



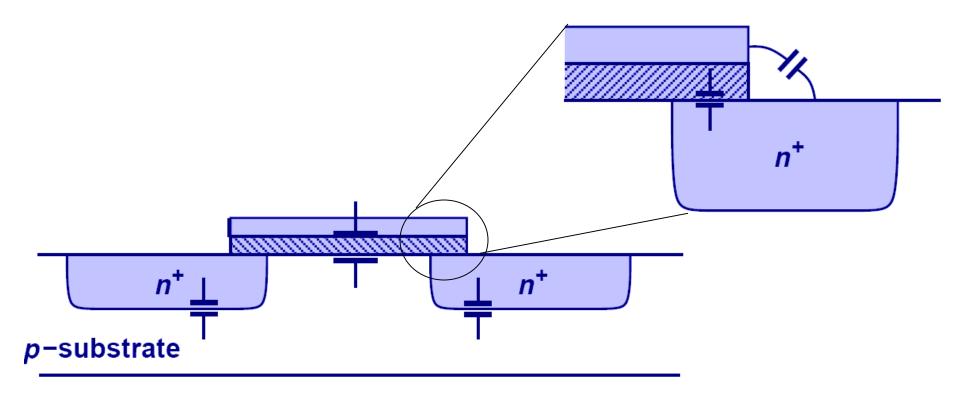
Since an integrated bipolar circuit is fabricated on top of a substrate, another junction capacitance exists between the collector and substrate, namely C_{cs}.

Example: Capacitance Identification



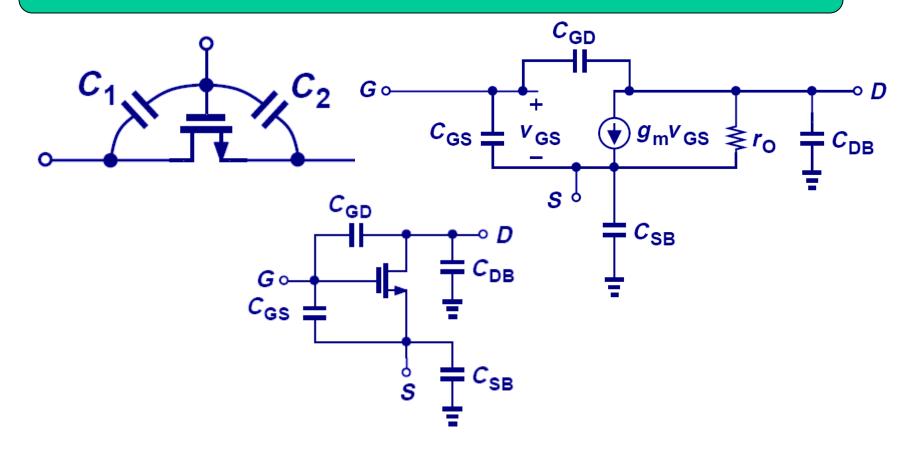


MOS Intrinsic Capacitances



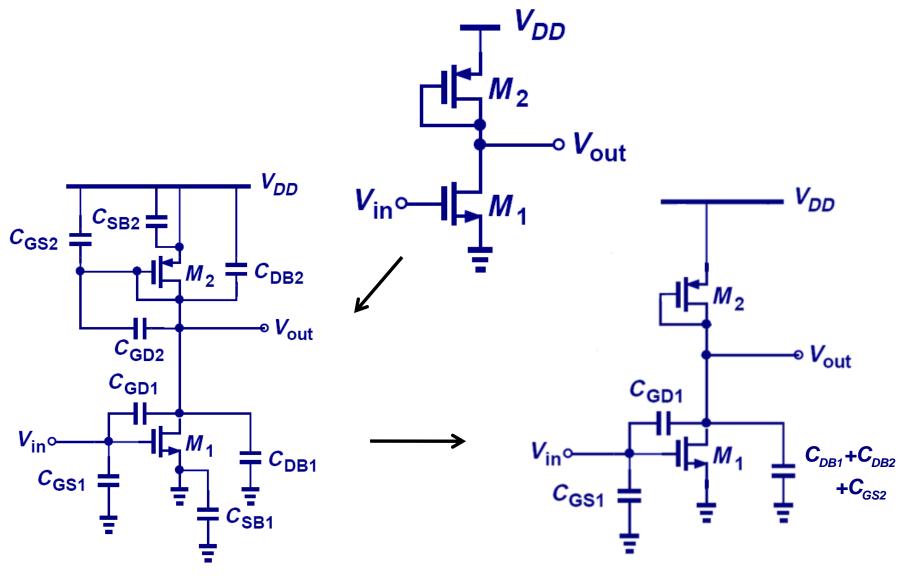
For a MOS, there exist oxide capacitance from gate to channel, junction capacitances from source/drain to substrate, and overlap capacitance from gate to source/drain.

Gate Oxide Capacitance Partition and Full Model



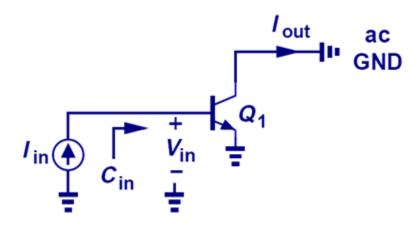
The gate oxide capacitance is often partitioned between source and drain. In saturation, $C_2 \sim C_{gate}$, and $C_1 \sim 0$. They are in parallel with the overlap capacitance to form C_{GS} and C_{GD} .

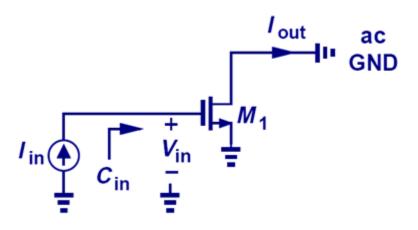
Example: Capacitance Identification



CH 11 Frequency Response

Transit Frequency





$$Z_{in} = \frac{1}{C_{\pi}s} \| r_{\pi}, \quad I_{out} = g_{m}I_{in}Z_{in}$$

$$\Rightarrow \frac{I_{out}}{I_{in}} = \frac{g_{m}r_{\pi}}{r_{\pi}C_{\pi}s + 1} = \frac{\beta}{r_{\pi}C_{\pi}s + 1}$$

$$\frac{I_{out}}{I_{in}} = 1 \quad \Rightarrow \quad r_{\pi}^{2}C_{\pi}^{2}\omega_{T}^{2} = \beta^{2} - 1 \approx \beta^{2}$$

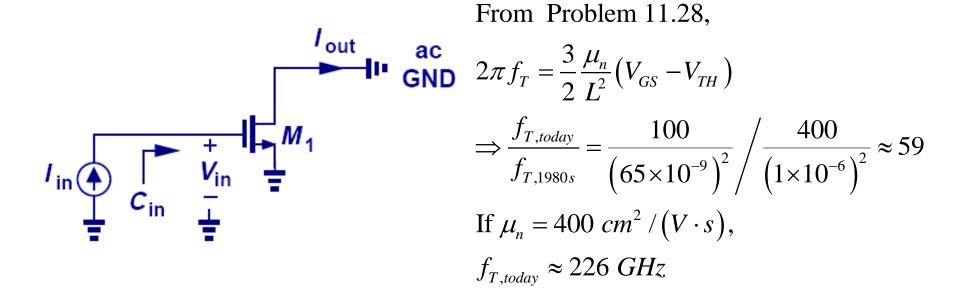
$$\Rightarrow \omega_{T} = 2\pi f_{T} \approx \frac{g_{m}}{C}$$

The transit frequency of MOSFETs is obtained in a similar fashion.

$$\omega_T = 2\pi f_T \approx \frac{g_m}{C_{GS}}$$

Transit frequency, f_T, is defined as the frequency where the current gain from input to output drops to 1.

Example: Transit Frequency Calculation



From 1μm in the late 1980s to 65nm today. Also, the inevitable reduction of the supply voltage has reduced the gate-source overdrive voltage from about 400mV to 100mV. By what factor has the f_τ of MOSFETs increased?

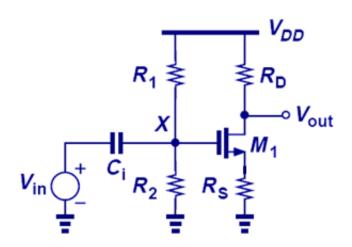
Analysis Summary

- The frequency response refers to the magnitude of the transfer function.
- ➤ Bode's approximation simplifies the plotting of the frequency response if poles and zeros are known.
- In general, it is possible to associate a pole with each node in the signal path.
- Miller's theorem helps to decompose floating capacitors into grounded elements.
- ➤ Bipolar and MOS devices exhibit various capacitances that limit the speed of circuits.

High Frequency Circuit Analysis Procedure

- Determine which capacitor impact the low-frequency region of the response and calculate the low-frequency pole (neglect transistor capacitance).
- Calculate the midband gain by replacing the capacitors with short circuits (neglect transistor capacitance).
- Include transistor capacitances.
- Merge capacitors connected to AC grounds and omit those that play no role in the circuit.
- Determine the high-frequency poles and zeros.
- Plot the frequency response using Bode's rules or exact analysis.

Frequency Response of CS Stage

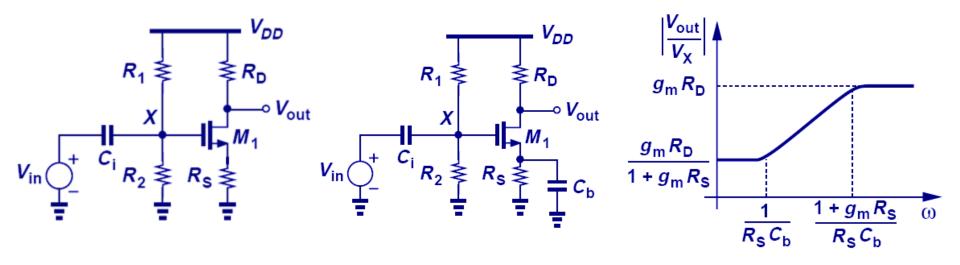


$$\frac{V_X}{V_{in}}(s) = \frac{R_1 \| R_2}{R_1 \| R_2 + \frac{1}{C_i s}} = \frac{\left(R_1 \| R_2\right) C_i s}{\left(R_1 \| R_2\right) C_i s + 1}$$

Thus,
$$\frac{1}{2\pi \left[\left(R_1 \| R_2 \right) C_i \right]} < f_{sig, min}$$

- Ci acts as a high pass filter.
- Lower cut-off frequency must be lower than the lowest signal frequency $f_{sig,min}$ (20 Hz in audio applications).

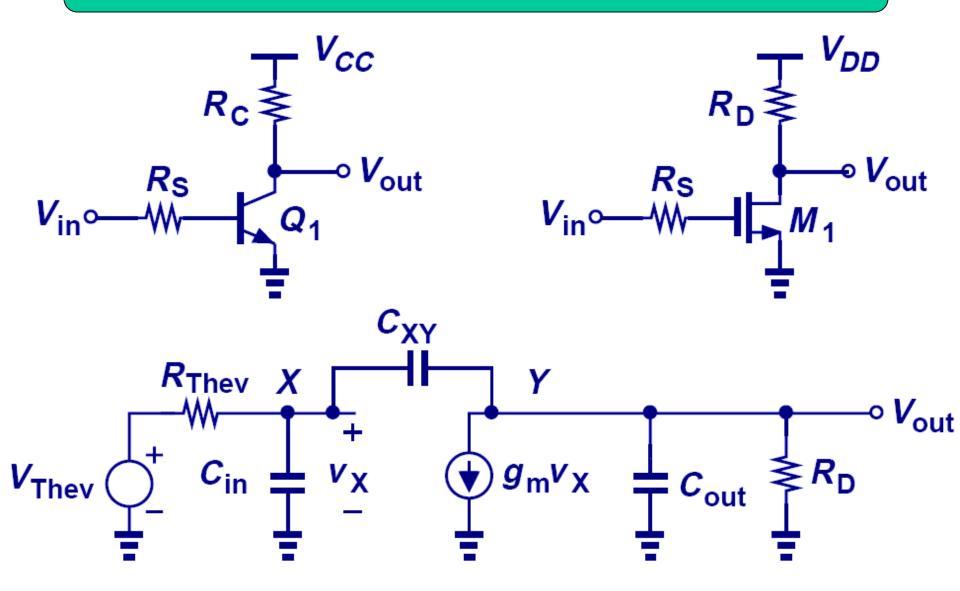
Frequency Response of CS Stage with Bypassed Degeneration



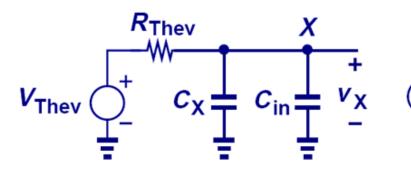
$$\frac{V_{out}}{V_X}(s) = \frac{-R_D}{R_S + \frac{1}{g_m}} \qquad \frac{V_{out}}{V_X}(s) = \frac{-R_D}{R_S || \frac{1}{C_b s} + \frac{1}{g_m}} = \frac{-g_m R_D (R_S C_b s + 1)}{R_S C_b s + g_m R_S + 1}$$

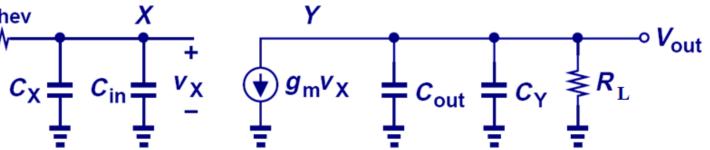
- ➤ In order to increase the midband gain, a capacitor C_b is placed in parallel with R_s.
- The pole frequency must be well below the lowest signal frequency to avoid the effect of degeneration.

Unified Model for CE and CS Stages



Unified Model Using Miller's Theorem





$$\left|\omega_{p,in}\right| = \frac{1}{R_{Thev}\left[C_{in} + \left(1 + g_{m}R_{L}\right)C_{XY}\right]}$$

$$\left|\omega_{p,out}\right| = \frac{1}{R_L \left[C_{out} + \left(1 + \frac{1}{g_m R_L}\right)C_{XY}\right]}$$

CE Stage

$$V_{\text{Thev}} = V_{\text{in}} \frac{r_{\pi}}{r_{\pi} + R_{\text{S}}}$$
 $R_{\text{Thev}} = R_{\text{S}} || r_{\pi}$
 $C_{\text{X}} = C_{\mu} (1 + g_{\text{m}} R_{\text{L}})$
 $C_{\text{Y}} = C_{\mu} (1 + \frac{1}{g_{\text{m}} R_{\text{L}}})$

$$V_{\mathsf{Thev}} = V_{\mathsf{in}}$$

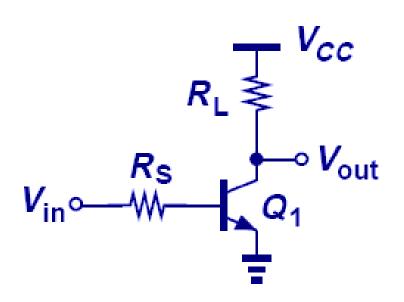
$$R_{\text{Thev}} = R_{\text{S}}$$

$$C_{\rm X} = C_{\rm GD} \left(1 + g_{\rm m} R_{\rm T}\right)$$

$$C_{\rm Y} = C_{\rm GD} \left(1 + \frac{1}{g_{\rm m} R_{\rm L}}\right)$$

Example: CE Stage

 \triangleright (a) Calculate the input and output poles if R_L=2 kΩ. Which node appears as the speed bottleneck?



$$\left|\omega_{p,in}\right| = \frac{1}{\left(R_{S} \left\|r_{\pi}\right)\left[C_{\pi} + \left(1 + g_{m}R_{L}\right)C_{\mu}\right]}$$

$$\left|\omega_{p,out}\right| = \frac{1}{R_L \left[C_{CS} + \left(1 + \frac{1}{g_m R_L}\right)C_{\mu}\right]}$$

$$R_S = 200 \ \Omega, \quad I_C = 1 \ \text{mA}$$

 $\beta = 100, \quad C_{\pi} = 100 \ \text{fF}$
 $C_{\mu} = 20 \ \text{fF}, \quad C_{CS} = 30 \ \text{fF}$

$$\left|\omega_{\text{p,in}}\right| = 2\pi \times (516 \text{ MHz})$$

 $\left|\omega_{\text{p,out}}\right| = 2\pi \times (1.59 \text{ GHz})$

Example: CE Stage - cont'd

(b) Is it possible to choose R_L such that the output pole limits the bandwidth?

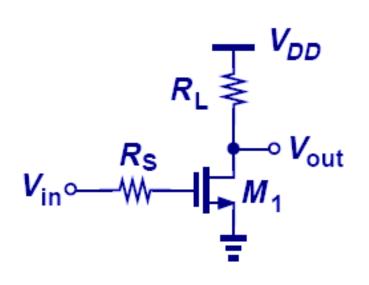
$$\begin{aligned} &\left|\omega_{p,in}\right| > \left|\omega_{p,out}\right| \\ &\Rightarrow \frac{1}{\left(R_{S} \left\|r_{\pi}\right)\left[C_{\pi} + \left(1 + g_{m}R_{L}\right)C_{\mu}\right]} > \frac{1}{R_{L}\left[C_{CS} + \left(1 + \frac{1}{g_{m}R_{L}}\right)C_{\mu}\right]} \end{aligned}$$

$$\text{If } g_{m}R_{L} \gg 1,$$

$$\Rightarrow \left[C_{CS} + C_{\mu} - g_{m}\left(R_{S} \left\|r_{\pi}\right)C_{\mu}\right]R_{L} > \left(R_{S} \left\|r_{\pi}\right)C_{\pi}\right]$$

With the values assumed in this example, the left-hand side is negative, implying that no solution exists. Thus, the input pole remains the speed bottleneck.

Example: Half Width CS Stage

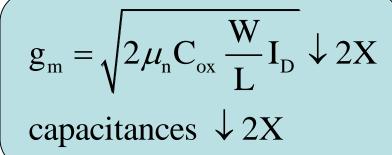


$$\left|\omega_{p,in}\right| = \frac{1}{R_{S}\left[\frac{C_{in}}{2} + \left(1 + \frac{g_{m}R_{L}}{2}\right)\frac{C_{XY}}{2}\right]}$$

$$\left|\omega_{p,out}\right| = \frac{1}{R_{L}\left[\frac{C_{out}}{2} + \left(1 + \frac{2}{g_{m}R_{L}}\right)\frac{C_{XY}}{2}\right]}$$

$$W \downarrow 2X$$

bias current $\downarrow 2X$



bandwidth $\uparrow 2X$ gain $\downarrow 2X$ gain•bandwidth \rightarrow constant

Direct Analysis of CE and CS Stages

$$V_{\text{Thev}} = \begin{bmatrix} C_{\text{XY}} & C_{\text{NI}} & C_{\text{Vout}} \\ C_{\text{in}} & C_{\text{in}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{Out}} \end{bmatrix} = \begin{bmatrix} C_{\text{Out}} & C_{\text{Out}} \\ C_{\text{Out}} & C_{\text{O$$

At Node Y:
$$(V_X - V_{out})C_{XY}s = g_m V_X + V_{out} \left(\frac{1}{R_L} + C_{out}s\right) \Rightarrow V_X = V_{out} \frac{C_{XY}s + \frac{1}{R_L} + C_{out}s}{C_{XY}s - g_m}$$

At Node X:
$$(V_{out} - V_X)C_{XY}s = V_XC_{in}s + \frac{V_X - V_{Thev}}{R_{Thev}}$$

$$\Rightarrow V_{out}C_{XY}s - \left(C_{XY}s + C_{in}s + \frac{1}{R_{Thev}}\right)\frac{C_{XY}s + \frac{1}{R_L} + C_{out}s}{C_{XY}s - g_m}V_{out} = \frac{-V_{Thev}}{R_{Thev}}$$

$$\Rightarrow \frac{\left(V_{out}\right)\left(s\right) = \frac{\left(C_{XY}s - g_{m}\right)R_{L}}{as^{2} + bs + 1} \text{ where } a = R_{Thev}R_{L}\left(C_{in}C_{XY} + C_{out}C_{XY} + C_{in}C_{out}\right),}$$

$$b = \left(1 + g_{m}R_{L}\right)C_{XY}R_{Thev} + R_{Thev}C_{in} + R_{L}\left(C_{XY} + C_{out}\right)$$

Direct Analysis of CE and CS Stages – cont'd

$$|\omega_z| = \frac{g_m}{C_{XY}}$$

$$as^{2} + bs + 1 = \left(\frac{s}{\omega_{p1}} + 1\right)\left(\frac{s}{\omega_{p2}} + 1\right) = \frac{s^{2}}{\omega_{p1}\omega_{p2}} + \left(\frac{1}{\omega_{p1}} + \frac{1}{\omega_{p2}}\right)s + 1$$

if
$$\omega_{p2} \gg \omega_{p1} \implies \omega_{p1}^{-1} + \omega_{p2}^{-1} \approx \omega_{p1}^{-1}$$
 Dominant-pole approximation

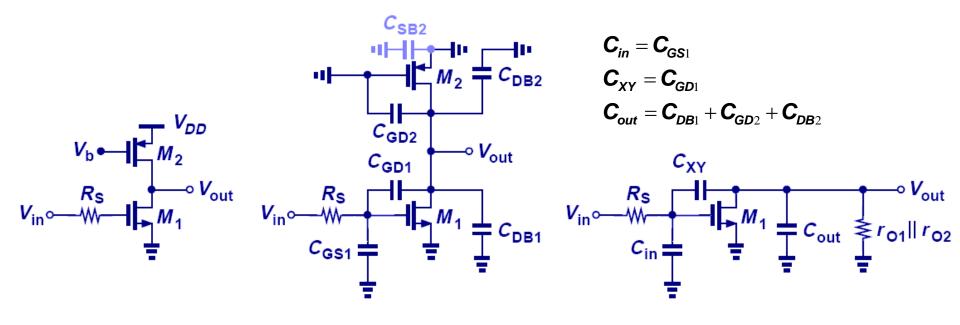
$$\Rightarrow b = \frac{1}{\omega_{p1}}$$

$$\left| \omega_{p1} \right| = \frac{1}{\left(1 + g_{m} R_{L} \right) C_{XY} R_{Thev} + R_{Thev} C_{in} + R_{L} \left(C_{XY} + C_{out} \right)}$$

$$\left| \omega_{p2} \right| = \frac{b}{a} = \frac{\left(1 + g_{m} R_{L} \right) C_{XY} R_{Thev} + R_{Thev} C_{in} + R_{L} \left(C_{XY} + C_{out} \right)}{R_{Thev} R_{L} \left(C_{in} C_{XY} + C_{out} C_{XY} + C_{in} C_{out} \right)}$$

Direct analysis yields different pole locations and an extra zero.

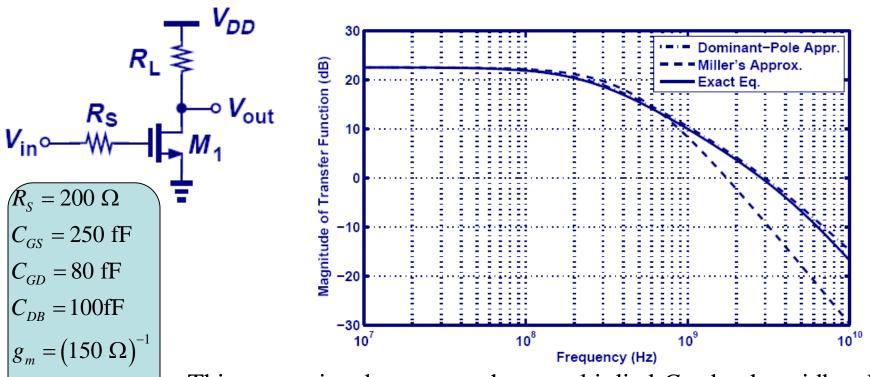
Example: Dominant-pole approximation



$$\omega_{p1} \approx \frac{1}{\left[1 + g_{m1}(r_{O1} \parallel r_{O2})\right]C_{XY}R_S + R_SC_{in} + (r_{O1} \parallel r_{O2})(C_{XY} + C_{out})}$$

$$\omega_{p2} \approx \frac{\left[1 + g_{m1}(r_{O1} \parallel r_{O2})\right]C_{XY}R_S + R_SC_{in} + (r_{O1} \parallel r_{O2})(C_{XY} + C_{out})}{R_S(r_{O1} \parallel r_{O2})(C_{in}C_{XY} + C_{out}C_{XY} + C_{in}C_{out})}$$

Example: Comparison Between Different Methods



This error arises because we have multiplied C_{GD} by the midband gain $(1+g_m R_L)$ rather than the gain at high frequencies.

Miller's $\left|\omega_{p,in}\right| = 2\pi \times (571 \text{ MHz})$ $\left|\omega_{p,out}\right| = 2\pi \times (428 \text{ MHz})$

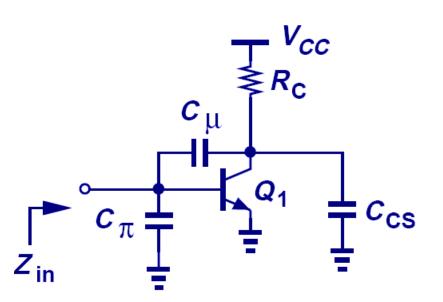
 $\lambda = 0$

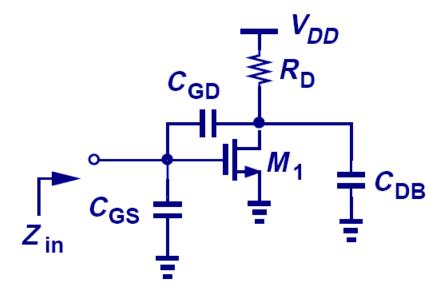
 $R_r = 2 \text{ k}\Omega$

$$\frac{\textit{Exact}}{\left|\omega_{p,in}\right| = 2\pi \times (264 \text{ MHz})}$$
$$\left|\omega_{p,out}\right| = 2\pi \times (4.53 \text{ GHz})$$

Dominant Pole $\left|\omega_{p,in}\right| = 2\pi \times (249 \text{ MHz})$ $\left|\omega_{p,out}\right| = 2\pi \times (4.79 \text{ GHz})$

Input Impedance of CE and CS Stages

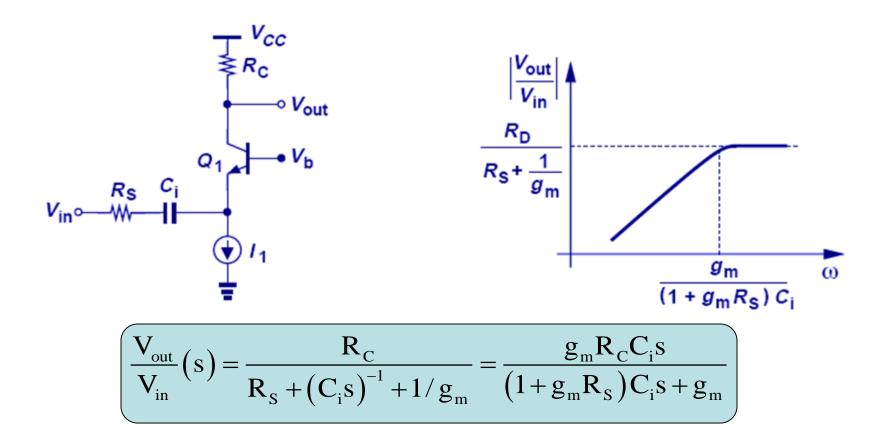




$$Z_{in} \approx \frac{1}{\left[C_{\pi} + \left(1 + g_{m}R_{C}\right)C_{\mu}\right]s} \parallel r_{\pi}$$

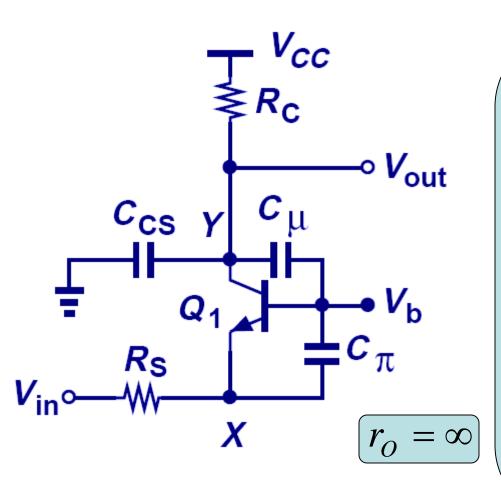
$$\frac{1}{(1 + g_m R_C)C_{\mu}]s} \| r_{\pi} \| Z_{in} \approx \frac{1}{[C_{GS} + (1 + g_m R_D)C_{GD}]s}$$

Low Frequency Response of CB and CG Stages



As with CE and CS stages, the use of capacitive coupling leads to low-frequency roll-off in CB and CG stages (although a CB stage is shown above, a CG stage is similar).

Frequency Response of CB Stage



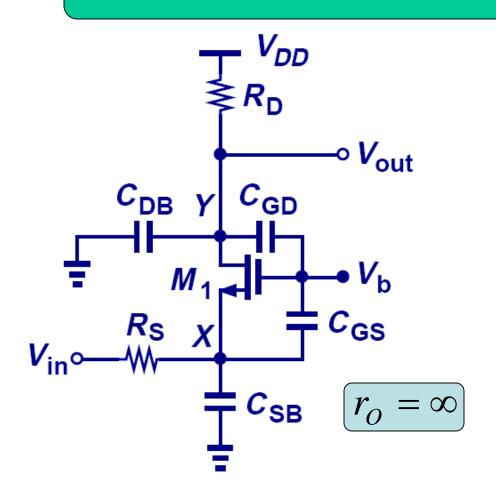
$$\omega_{p,X} = \frac{1}{\left(R_S \parallel \frac{1}{g_m}\right)C_X}$$

$$C_X = C_{\pi}$$

$$\omega_{p,Y} = \frac{1}{R_C C_Y}$$

$$C_Y = C_{\mu} + C_{CS}$$

Frequency Response of CG Stage



$$\omega_{p,X} = \frac{1}{\left(R_S \parallel \frac{1}{g_m}\right)C_X}$$

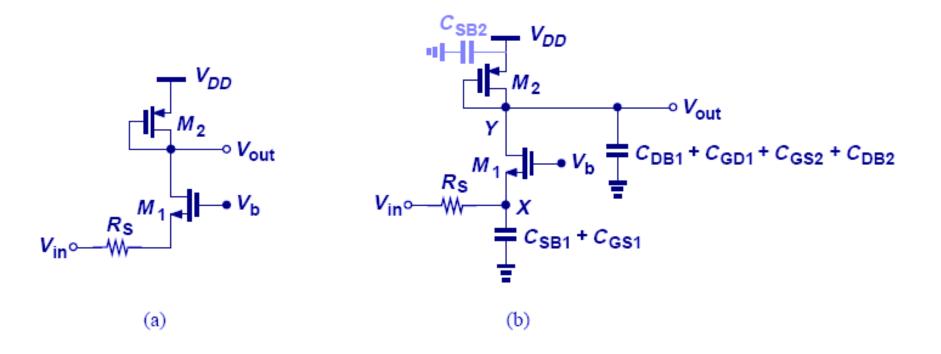
$$C_X = C_{GS} + C_{SB}$$

$$\omega_{p,Y} = \frac{1}{R_D C_Y}$$

$$C_Y = C_{GD} + C_{DB}$$

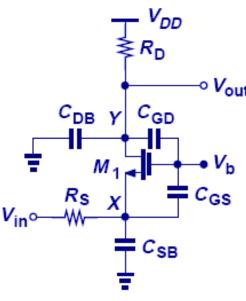
 \triangleright Similar to a CB stage, the input pole is on the order of f_T , so rarely a speed bottleneck.

Example: CG Stage Pole Identification

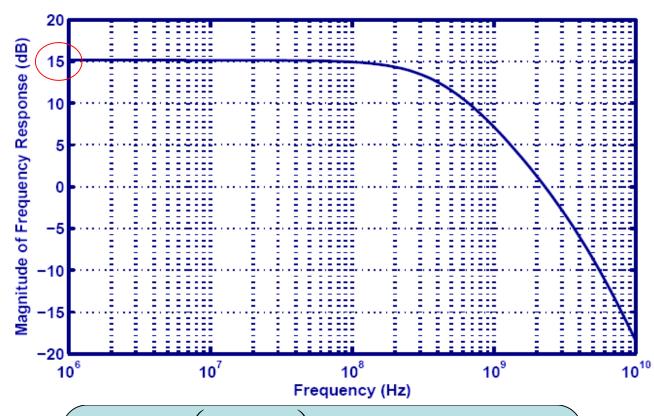


$$\omega_{p,X} = \frac{1}{\left(R_{S} \parallel \frac{1}{g_{m1}}\right) \left(C_{SB1} + C_{GS1}\right)} \quad \omega_{p,Y} = \frac{1}{\frac{1}{g_{m2}} \left(C_{DB1} + C_{GD1} + C_{GS2} + C_{DB2}\right)}$$

Example: Frequency Response of CG Stage



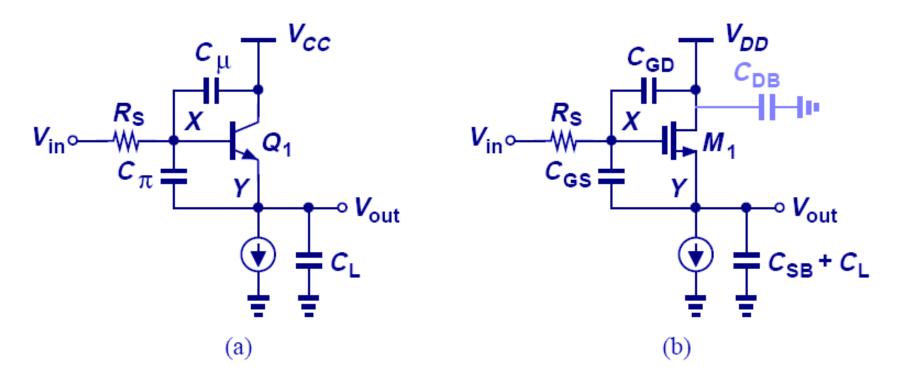
$$R_S = 200 \Omega$$
 $C_{GS} = 250 \text{ fF}$
 $C_{GD} = 80 \text{ fF}$
 $C_{DB} = 100 \text{ fF}$
 $g_m = (150 \Omega)^{-1}$
 $\lambda = 0$
 $R_D = 2 \text{ k}\Omega$



$$\left| \left| \omega_{p,X} \right| = 1 / \left(R_S \parallel \frac{1}{g_m} \right) C_X = 2\pi \times (5.31 \text{ GHz}) \right|$$

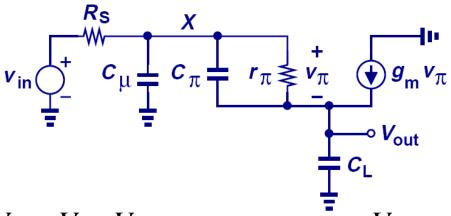
$$\left| \left| \omega_{p,Y} \right| = R_L / C_Y = 2\pi \times (442 \text{ MHz})$$

Emitter and Source Followers



- ➤ The following will discuss the frequency response of emitter and source followers using direct analysis.
- Figure 2. Emitter follower is treated first and source follower is derived easily by allowing r_{π} to go to infinity.

Direct Analysis of Emitter Follower



At node X:
$$\frac{V_{out} + V_{\pi} - V_{in}}{R_{S}} + (V_{out} + V_{\pi})C_{\mu}s + \frac{V_{\pi}}{r_{\pi}} + V_{\pi}C_{\pi}s = 0$$
At output node:
$$\frac{V_{\pi}}{r_{\pi}} + V_{\pi}C_{\pi}s + g_{m}V_{\pi} = V_{out}C_{L}s \implies V_{\pi} = \frac{V_{out}C_{L}s}{1 + C_{\pi}s + g_{\pi}}$$

$$\frac{V_{\pi}}{r_{\pi}} + V_{\pi}C_{\pi}s + g_{m}V_{\pi} = V_{out}C_{L}s \implies V_{\pi} = \frac{V_{out}C_{L}s}{\frac{1}{r_{\pi}} + C_{\pi}s + g_{m}}$$

$$\frac{V_{out}}{V_{in}} = \frac{1 + \frac{C_{\pi}}{g_m} s}{as^2 + bs + 1}$$

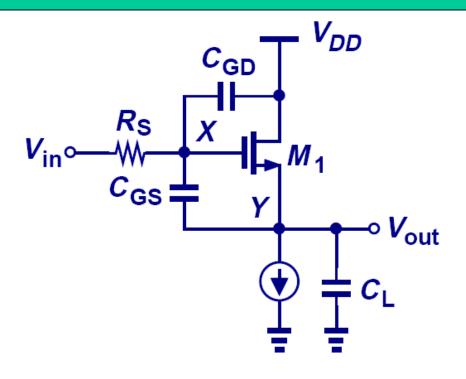
with
$$r_{\pi} \gg g_{m}^{-1}$$

$$\left|\omega_{z}\right| = \frac{g_{m}}{C_{\pi}} \approx f_{T}$$

$$\frac{V_{out}}{V_{in}} = \frac{1 + \frac{m}{s}S}{as^2 + bs + 1} \quad \text{with } r_{\pi} \gg g_m^{-1} \quad \text{where } a = \frac{R_S}{g_m} \left(C_{\mu} C_{\pi} + C_{\mu} C_L + C_{\pi} C_L \right)$$

$$b = R_S C_{\mu} + \frac{C_{\pi}}{g_m} + \left(1 + \frac{R_S}{r_{\pi}}\right) \frac{C_L}{g_m}$$

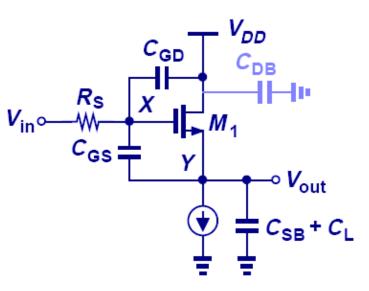
Direct Analysis of Source Follower Stage



$$\frac{1 + \frac{C_{GS}}{g_{m}}s}{V_{in}} = \frac{1 + \frac{C_{GS}}{g_{m}}s}{as^{2} + bs + 1} \qquad a = \frac{R_{S}}{g_{m}}\left(C_{GD}C_{GS} + C_{GD}\left(C_{SB} + C_{L}\right) + C_{GS}\left(C_{SB} + C_{L}\right)\right)$$

$$b = R_{S}C_{GD} + \frac{C_{GD} + C_{SB} + C_{L}}{g_{m}}$$

Example: Frequency Response of Source Follower



$$R_S = 200 \Omega$$

$$C_L = 100 \text{ fF}$$

$$C_{GS} = 250 \text{ fF}$$

$$C_{GD} = 80 \text{ fF}$$

$$C_{DB} = 100 \text{ fF}$$

$$g_m = (150 \Omega)^{-1}$$

$$\lambda = 0$$

$$a = 2.58 \times 10^{-21} s^{-2}$$

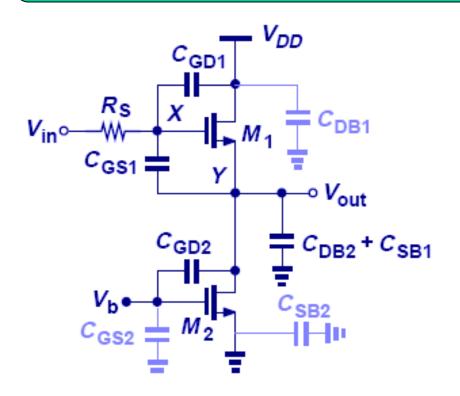
$$b = 5.8 \times 10^{-11} s$$

$$\omega_z = g_m / C_{GS} = 2\pi \times (4.24 \text{ GHz})$$

$$\omega_{p1} = 2\pi \left[1.79 \text{ GHz} + j(2.57 \text{ GHz}) \right]$$

$$\omega_{p2} = 2\pi \left[1.79 \text{ GHz} - j(2.57 \text{ GHz}) \right]$$

Example: Source Follower

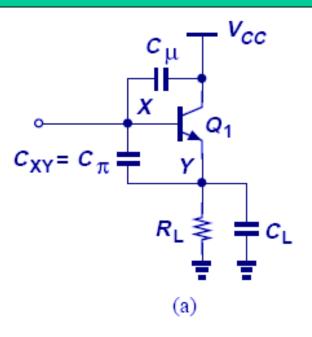


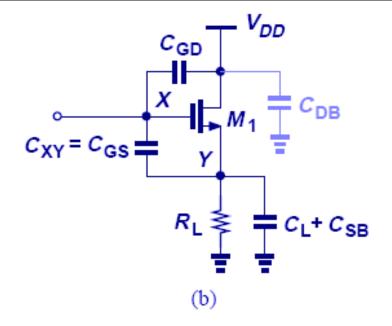
$$\frac{V_{out}}{V_{in}} = \frac{1 + \frac{C_{GS}}{g_m}s}{as^2 + bs + 1}$$

$$a = \frac{R_S}{g_{m1}} \left[C_{GD1} C_{GS1} + (C_{GD1} + C_{GS1})(C_{SB1} + C_{GD2} + C_{DB2}) \right]$$

$$b = R_S C_{GD1} + \frac{C_{GD1} + C_{SB1} + C_{GD2} + C_{DB2}}{g_{m1}}$$

Input Capacitance of Emitter/Source Follower





$$A_{v} = \frac{R_{L}}{R_{L} + \frac{1}{\varrho}} \quad \Rightarrow \quad C_{X} = (1 - A_{v})C_{XY} = \frac{1}{1 + g_{m}R_{L}}C_{XY}$$

$$\therefore \left(C_{in} = \left(C_{\mu} \text{ or } C_{GD} \right) + \frac{C_{XY}}{1 + g_{m} R_{L}} \right)$$

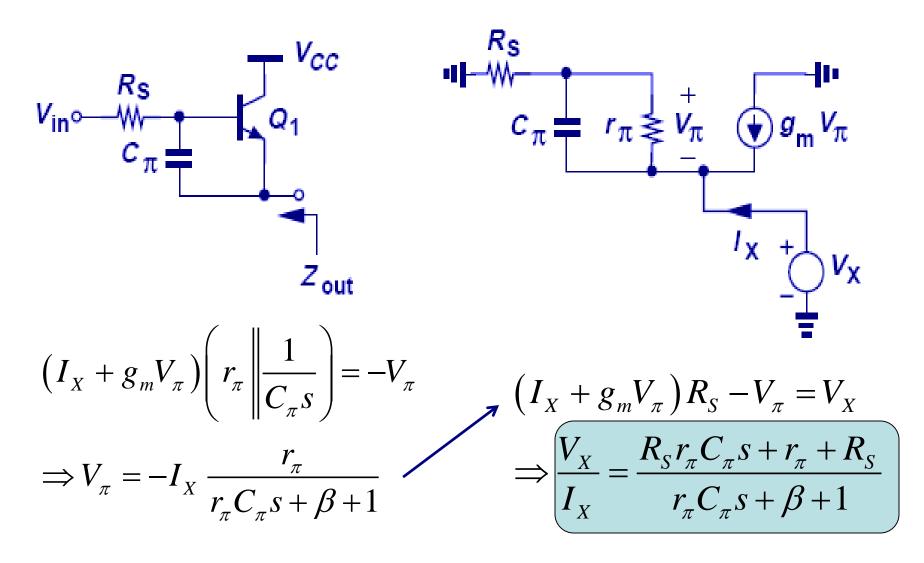
Example: Source Follower Input Capacitance

$$V_{\text{in}} = \frac{r_{O1} \| r_{O2}}{r_{O1} \| r_{O2} + \frac{1}{g_{m1}}}$$

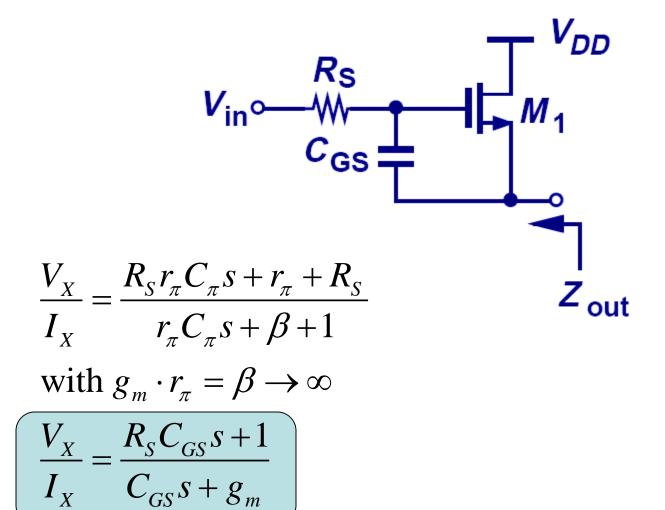
$$\Rightarrow C_{in} = C_{GD1} + (1 - A_{v}) C_{GS1}$$

$$= C_{GD1} + \frac{1}{1 + g_{m1} (r_{O1} \| r_{O2})} C_{GS1}$$

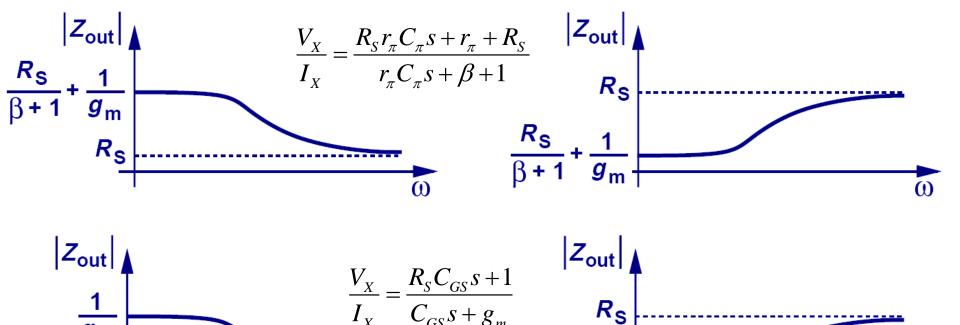
Output Impedance of Emitter Follower



Output Impedance of Source Follower

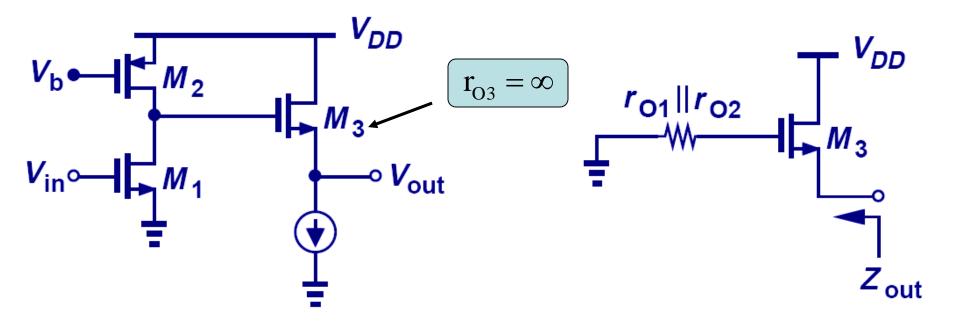


Active Inductor



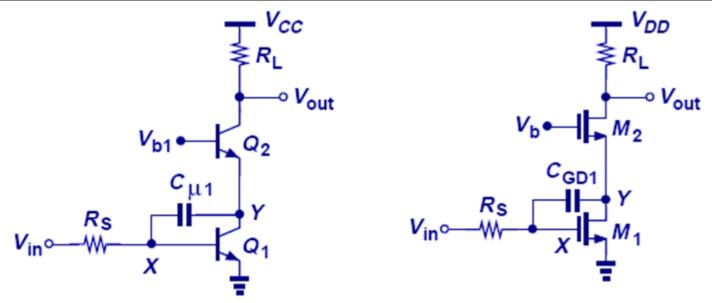
The plot above shows the output impedance of emitter and source followers. Since a follower's primary duty is to lower the driving impedance ($R_S > 1/g_m$), the "active inductor" characteristic on the right is usually observed.

Example: Output Impedance



$$\left(\frac{V_X}{I_X} = \frac{(r_{O1} \parallel r_{O2})C_{GS3}s + 1}{C_{GS3}s + g_{m3}}\right)$$

Frequency Response of Cascode Stage



Assuming $r_o = \infty$ for all transistors,

$$A_{v,XY} = \frac{-g_{m1}}{g_{m2}} \approx -1$$

$$C_{x} = (1 - A_{v,XY})C_{XY}$$

$$\approx 2 \cdot C_{XY}$$

For cascode stages, there are three poles and Miller multiplication is smaller than in the CE/CS stage.

Poles of Bipolar Cascode

$$\omega_{p,X} = \frac{1}{(R_S \parallel r_{\pi 1})(C_{\pi 1} + 2C_{\mu 1})}$$

$$v_{cc}$$

$$R_L$$

$$v_{b1}$$

$$v_{cc}$$

$$R_L$$

$$v_{out}$$

$$v_{out}$$

$$v_{in}$$

$$v_{in}$$

$$v_{m1}$$

$$v_{m2}$$

$$v_{m1}$$

$$v_{m1}$$

$$v_{m2}$$

$$v_{m1}$$

$$v_{m2}$$

$$v_{m1}$$

$$v_{m2}$$

$$v_{m3}$$

$$v_{m4}$$

$$v_{m1}$$

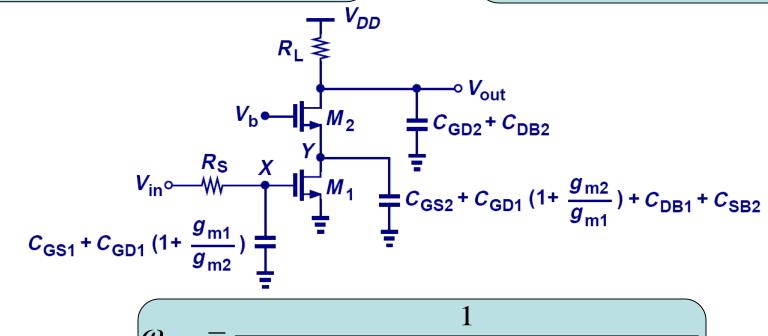
$$v_{m4}$$

$$v_{m4$$

Poles of MOS Cascode

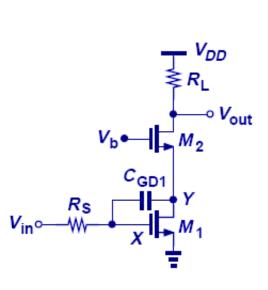
$$\omega_{p,X} = \frac{1}{R_{S} \left[C_{GS1} + \left(1 + \frac{g_{m1}}{g_{m2}} \right) C_{GD1} \right]}$$

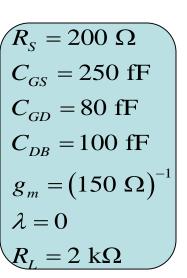
$$o_{p,out} = \frac{1}{R_L (C_{DB2} + C_{GD2})}$$

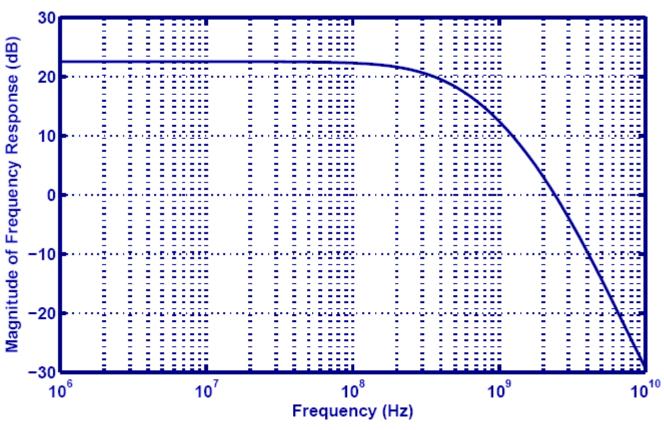


$$\omega_{p,Y} = \frac{1}{\frac{1}{g_{m2}} \left[C_{DB1} + C_{GS2} + \left(1 + \frac{g_{m2}}{g_{m1}} \right) C_{GD1} \right]}$$

Example: Frequency Response of Cascode







$$\left|\omega_{p,X}\right| = 2\pi \times (1.95 \text{ GHz})$$

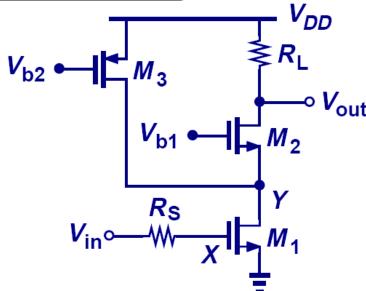
 $\left|\omega_{p,Y}\right| = 2\pi \times (1.73 \text{ GHz})$
 $\left|\omega_{p,out}\right| = 2\pi \times (442 \text{ MHz})$

CH 11 Frequency Response

MOS Cascode Example

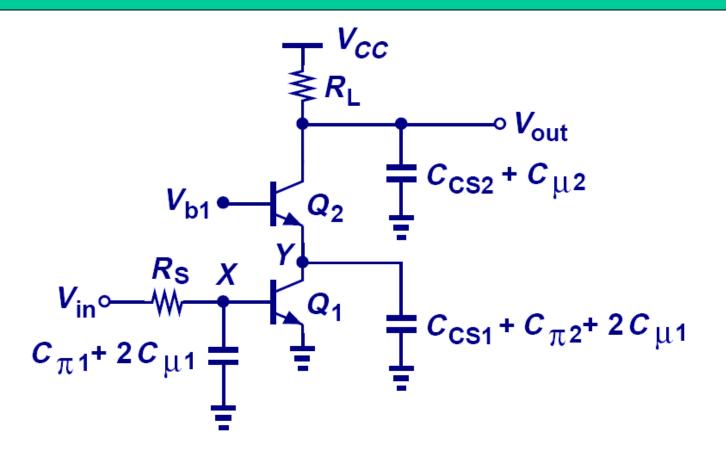
$$\omega_{p,X} = \frac{1}{R_{S} \left[C_{GS1} + \left(1 + \frac{g_{m1}}{g_{m2}} \right) C_{GD1} \right]}$$

$$\omega_{p,out} = \frac{1}{R_L (C_{DB2} + C_{GD2})}$$



$$\omega_{p,Y} = \frac{1}{\frac{1}{g_{m2}} \left[C_{DB1} + C_{GS2} + \left(1 + \frac{g_{m2}}{g_{m1}} \right) C_{GD1} + C_{SB2} + C_{GD3} + C_{DB3} \right]}$$

I/O Impedance of Bipolar Cascode



$$Z_{in} = r_{\pi 1} \parallel \frac{1}{(C_{\pi 1} + 2C_{\mu 1})s}$$

CH 11 Frequency Response

$$Z_{out} = R_L \parallel \frac{1}{\left(C_{\mu 2} + C_{CS2}\right)s}$$

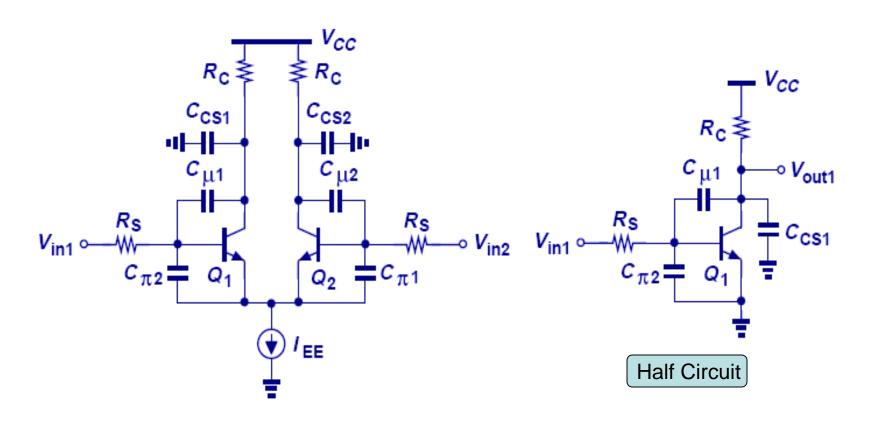
I/O Impedance of MOS Cascode

$$V_{\text{b}}$$
 V_{b}
 V_{b}
 V_{b}
 V_{out}
 V_{out}
 V_{out}
 V_{in}
 $V_{\text{$

$$Z_{in} = \frac{1}{\left[C_{GS1} + \left(1 + \frac{g_{m1}}{g_{m2}}\right)C_{GD1}\right]s}$$

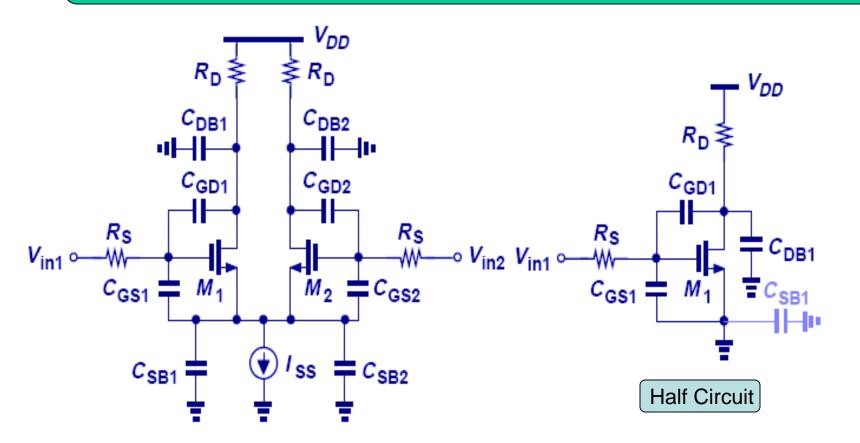
$$Z_{out} = R_L \parallel \frac{1}{(C_{GD2} + C_{DB2})s}$$

Bipolar Differential Pair Frequency Response



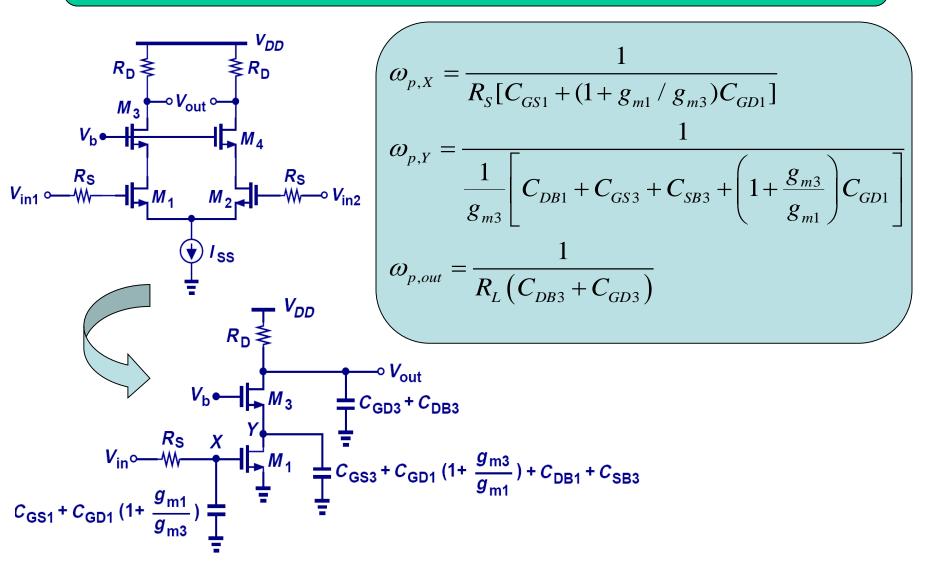
Since bipolar differential pair can be analyzed using half-circuit, its transfer function, I/O impedances, locations of poles/zeros are the same as that of the half circuit's.

MOS Differential Pair Frequency Response

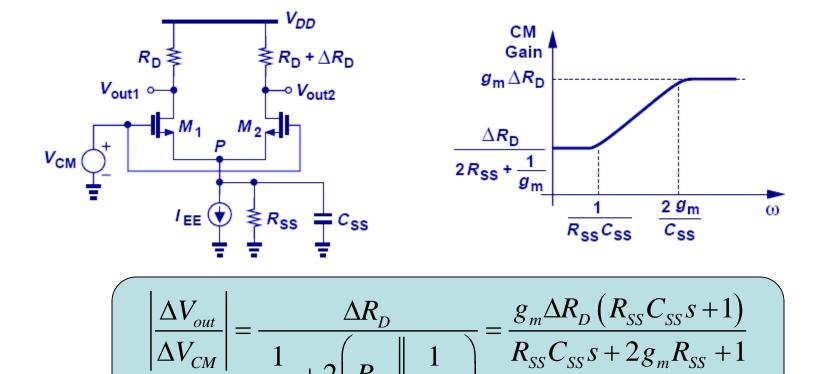


Since MOS differential pair can be analyzed using halfcircuit, its transfer function, I/O impedances, locations of poles/zeros are the same as that of the half circuit's.

Example: MOS Differential Pair

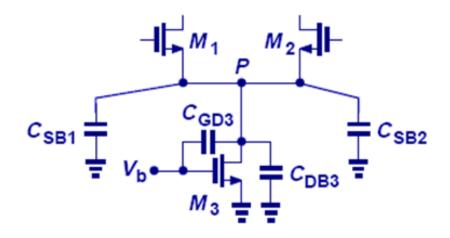


Common Mode Frequency Response



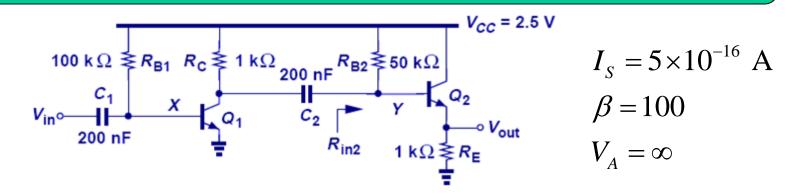
C_{ss} will lower the total impedance between point P to ground at high frequency, leading to higher CM gain which degrades the CM rejection ratio.

Tail Node Capacitance Contribution



- ➤ Source-Body Capacitance of M₁, M₂
- Drain-Body Capacitance of M₃
- Gate-Drain Capacitance of M₃

Example: Capacitive Coupling



For Q_1 , assuming $V_{BE1} = 800 \text{ mV}$,

$$I_{C1} = \beta \frac{V_{CC} - V_{BE1}}{R_{B1}} = 1.7 \text{ mA}$$

 $\Rightarrow V_{BE1} = V_T \ln (I_{C1} / I_{S1}) = 748 \text{ mV}$

$$\Rightarrow I_{C1} = 1.75 \text{ mA} \Rightarrow g_{m1} = (14.9 \Omega)^{-1}$$

$$\Rightarrow r_{\pi 1} = 1.49 \text{ k}\Omega$$

For Q_2 , assuming $V_{BE2} = 800 \text{mV}$,

$$V_{CC} = I_{B2}R_{B2} + V_{BE2} + R_E I_{C2}$$

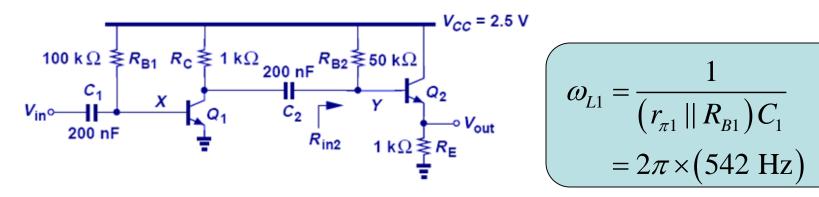
$$\Rightarrow I_{C2} = \frac{V_{CC} - V_{BE2}}{R_{B2} / \beta + R_E} = 1.13 \text{ mA}$$

Iteration yields

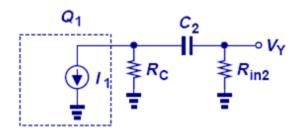
$$I_{C2} = 1.17 \text{ mA}, \ g_{m2} = (22.2 \ \Omega)^{-1}$$

 $\Rightarrow r_{\pi 2} = 2.22 \text{ k}\Omega$

Example: Capacitive Coupling – cont'd



$$\omega_{L1} = \frac{1}{\left(r_{\pi 1} \parallel R_{B1}\right) C_1}$$
$$= 2\pi \times (542 \text{ Hz})$$

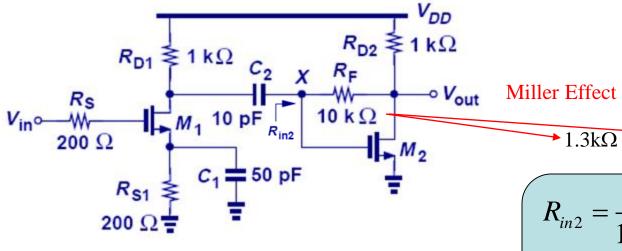


$$R_{in2} = R_{B2} \parallel [r_{\pi 2} + (\beta + 1)R_E]$$

$$V_{\text{Thev}}$$
 $\stackrel{+}{=}$ $\stackrel{R_{\text{C}}}{=}$ $\stackrel{C_2}{=}$ $\stackrel{V_{\text{Y}}}{=}$

$$\omega_{L2} = \frac{1}{\left(R_C + R_{in2}\right)C_2}$$
$$= 2\pi \times \left(22.9 \text{ Hz}\right)$$

Example: IC Amplifier – Low Frequency Behavior



From P35

$$\omega_{L1} = \frac{1}{\left(R_{S1} \| \frac{1}{g_{m1}}\right) C_1}$$

$$= \frac{g_{m1} R_{S1} + 1}{R_{S1} C_1}$$

$$= 2\pi \times (42.4 \text{ MHz})$$

$$R_{in2} = \frac{R_F}{1 - A_{v2}}$$

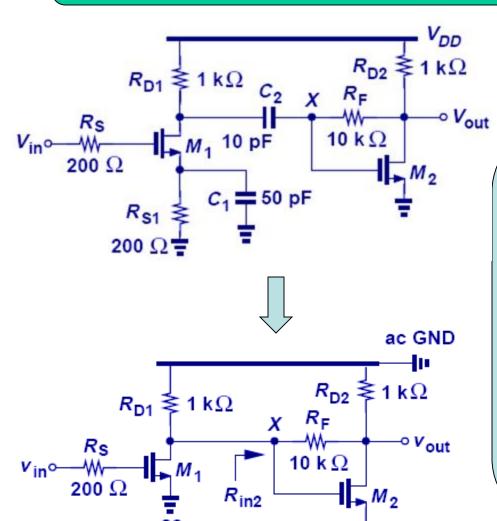
$$A_{v2} \approx -g_{m2}R_{D2} = -6.67$$

$$\Rightarrow R_{in2} = 1.30 \text{ k}\Omega$$

→ 8.7kΩ

$$\omega_{L2} = \frac{1}{\left(R_{D1} + R_{in2}\right)C_2}$$
$$= 2\pi \times \left(6.92 \text{ MHz}\right)$$

Example: IC Amplifier – Midband Behavior



$$\frac{v_{out}}{v_{in}} = \left(\frac{v_X}{v_{in}}\right) \times \left(\frac{v_{out}}{v_X}\right)$$

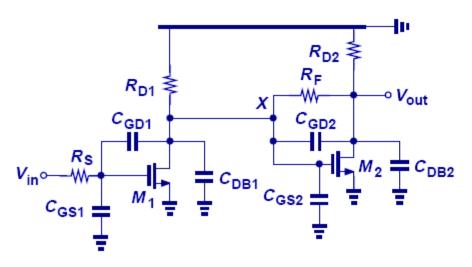
$$\frac{v_X}{v_{in}} = -g_{m1} \left(R_{D1} \parallel R_{in2}\right) = -3.77$$

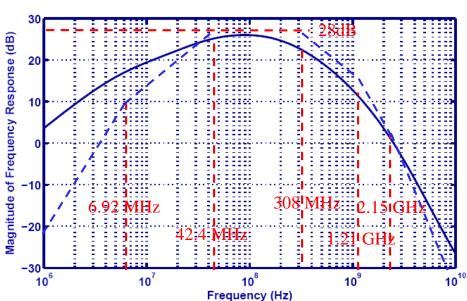
$$\frac{v_{out}}{v_X} \approx -g_{m2} R_{D2} = -6.67$$

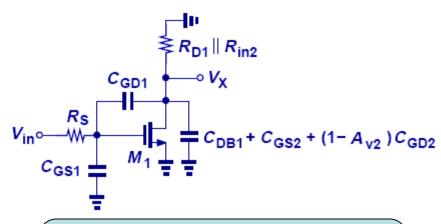
$$\Rightarrow \frac{v_{out}}{v_X} \approx 25.1$$

GND

Example: IC Amplifier – High Frequency Behavior







$$\left|\omega_{p1}\right| = 2\pi \times (308 \text{ MHz})$$

 $\left|\omega_{p2}\right| = 2\pi \times (2.15 \text{ GHz})$

With Miller effect,

$$(1 - A_{v2}^{-1})C_{GD2} \approx 1.15 \cdot C_{GD2}$$

$$\left|\omega_{p3}\right| = \frac{1}{R_{L2}(1.15 \cdot C_{GD2} + C_{DB2})}$$

= $2\pi \times (1.21 \,\text{GHz})$